

# S1107SXU40

## **Flat Base Rectifier Diode**

DS6222-1 February 2018 (LN35117)

#### FEATURES

- Low losses for high efficiency
- Hermetically sealed for long operational life
- Easily mounted down with 4 M8 bolts on 46mm centres
- Available with flying lead, full and half bar connections on request
- Available anode to base and cathode to base
- Selections available for parallel operation

#### **VOLTAGE RATINGS**

Part and Ordering Number	Repetitive Peak Voltages V <sub>RRM</sub> V	Conditions
S1107SXU40 to S1107SXU25	4000 to 2500	V <sub>RSM</sub> = V <sub>RRM</sub> +100V

### **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

S1107SXU40 for a 4000V anode to base device S1107SXD40 for a 4000V cathode to base device

#### **KEY PARAMETERS**

V <sub>RRM</sub>	
I <sub>F(AV)</sub>	
I <sub>FSM</sub>	

4000V 570A 12000A

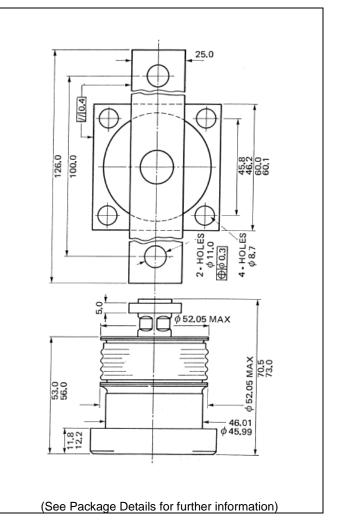


Fig. 1 Package outline

#### **CURRENT RATINGS**

T<sub>case</sub> = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units	
Single Sid	Single Side Cooled (Anode side)				
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load	570	А	
I <sub>F(RMS)</sub>	RMS value	-	895	А	
١ <sub>F</sub>	Continuous (direct) on-state current	-	750	A	

#### SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I <sub>FSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$	12	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_R = 50\% V_{RRM}$ - ¼ sine	0.72	MA <sup>2</sup> s

#### THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance – junction to heatsink	dc	-	0.065	°C/W
		Half wave		0.065	°C/W
		3 phase		0.078	°C/W
$T_{vj}$	Virtual junction temperature	On-state (conducting)	-	150	°C
		Reverse (blocking)	-	150	°C
T <sub>stg</sub>	Storage temperature range		-55	165	°C
Torque	Clamping torque		0	22	Nm

#### CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
$V_{FM}$	Forward voltage	At 1800A peak, T <sub>case</sub> = 150°C	-	1.55	V
I <sub>RM</sub>	Peak reverse current	At V <sub>DRM</sub> , T <sub>case</sub> = 150°C	-	50	mA
$Q_S$	Total stored charge	I <sub>F</sub> = 1000A, dI <sub>RR</sub> /dt =3A/µs	-	2000	μC
l <sub>rr</sub>	Peak reverse recovery current	$T_{case} = 150^{\circ}C, V_{R} = 100V$	-	80	А
V <sub>TO</sub>	Threshold voltage	At T <sub>vj</sub> = 150°C	-	0.75	V
۲ <sub>T</sub>	Slope resistance	At T <sub>vj</sub> = 150°C	-	0.44	mΩ

### CURVES

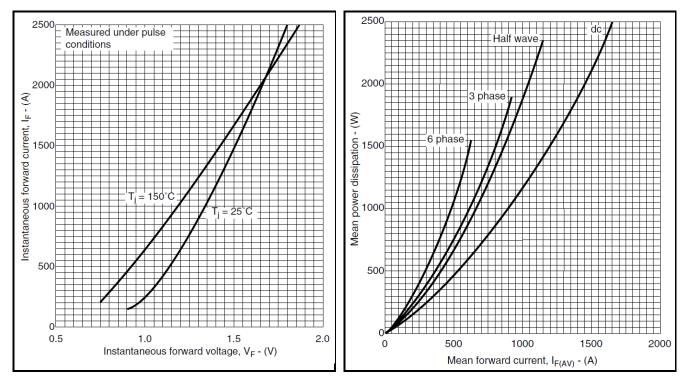
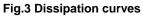


Fig.2 Maximum & minimum on-state characteristics



### S1107SXU40

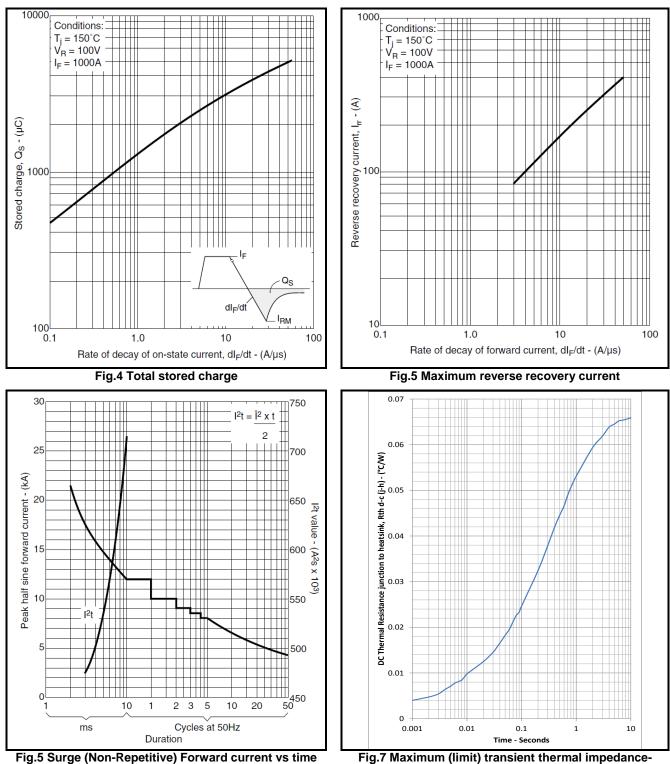
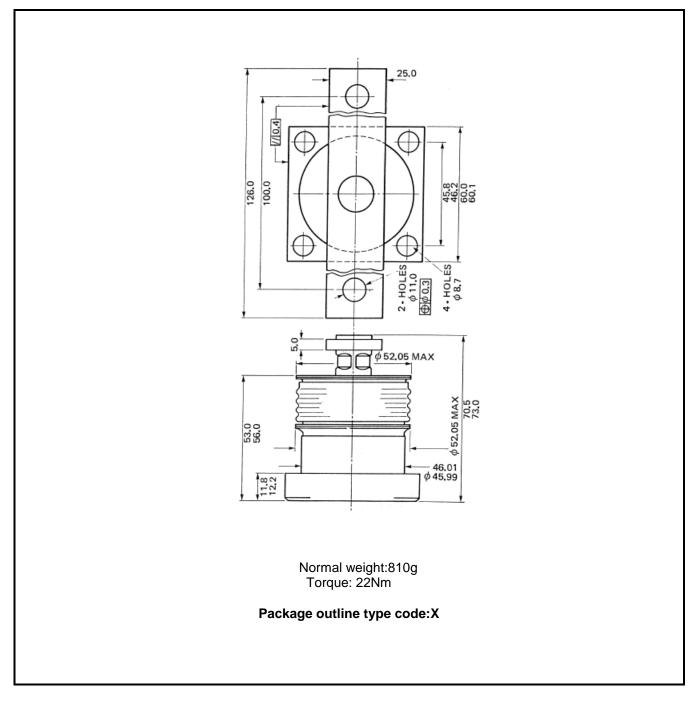


Fig.7 Maximum (limit) transient thermal impedancejunction to heatsink

### PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



#### Note:

Some packages may be supplied with gate and or tags.

#### S1107SXU40

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